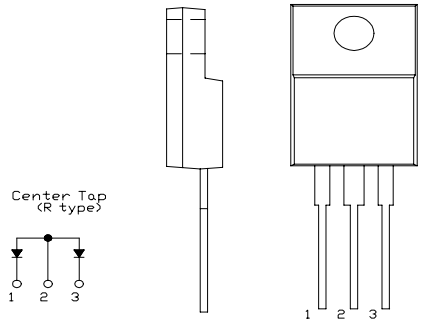
Nihon Inter Electronics Corporation

FRD Type : F10P20FR

OUTLINE DRAWING

FEATURES

* Fully Molded Isolation
* Dual Diodes – Anode Common
* Ultra – Fast Recovery
* Low Forward Voltage Drop
* High Surge Capability
* 200 Volts thru 600 Volts Types Available



Maximum Ratings

Approx Net Weight:1.75g

Rating	Symbol	F10P20FR			Unit
Repetitive Peak Reverse Voltage	V_{RRM}	200			V
Non-repetitive Peak Reverse Voltage	V_{RSM}	220			V
Average Rectified Output Current	I_O	10	Tc=117℃	50 Hz,Full Sine Wave Resistive Load	A
RMS Forward Current	$I_{F(RMS)}$	11.1			A
Surge Forward Current	I_{FSM}	80	50 Hz Full Sine Wave,1cycle Non-repetitive		A
Operating JunctionTemperature Range	Tjw	- 40 to + 150			℃
Storage Temperature Range	Tstg	- 40 to + 150			℃
Mounting torque		0.5	Recommended value		N•m

Electrical • Thermal Characteristics

Characteristics	Symbol	Conditions	Min.	Typ.	Max.	Unit
Peak Reverse Current	I_{RM}	Tj=25℃,V_{RM}=V_{RRM} per Arm	-	-	20	μA
Peak Forward Voltage	V_{FM}	Tj=25℃, I_{FM}=5A per Arm	-	-	0.98	V
Reverse Recovery Time	trr	I_{FM}= 5 A, -di/dt= 50 A/μs, Ta= 25℃	-	-	35	ns
Thermal Resistance	Rth(j-c)	Junction to Case	-	-	3	℃/W
	Rth(c-f)	Case to Fin			1.5	

F10P20FR OUTLINE DRAWING (Dimensions in mm)

